

## Supporting Information

### Room temperature ammonia gas sensing using mixed-valent $\text{CuCo}_2\text{O}_4$ nanoparticles: Performance enhancement through stoichiometry control

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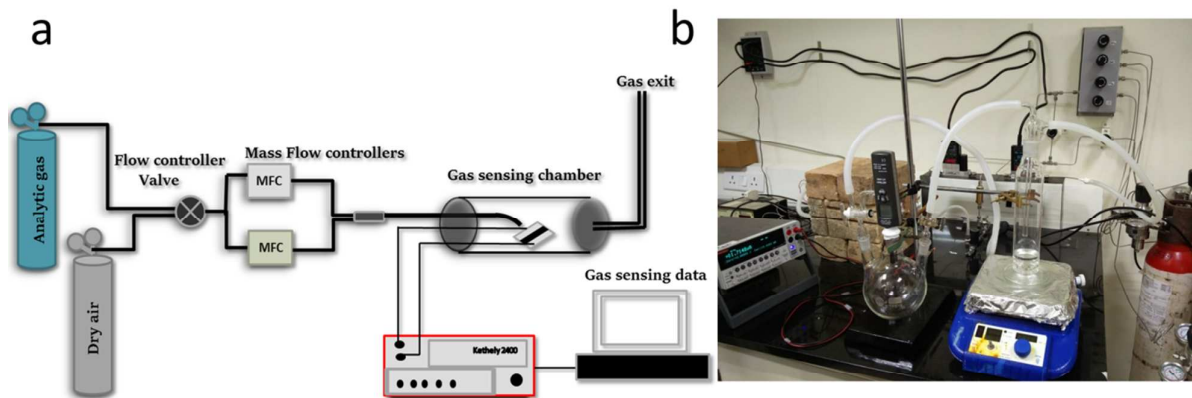
#Equal contribution

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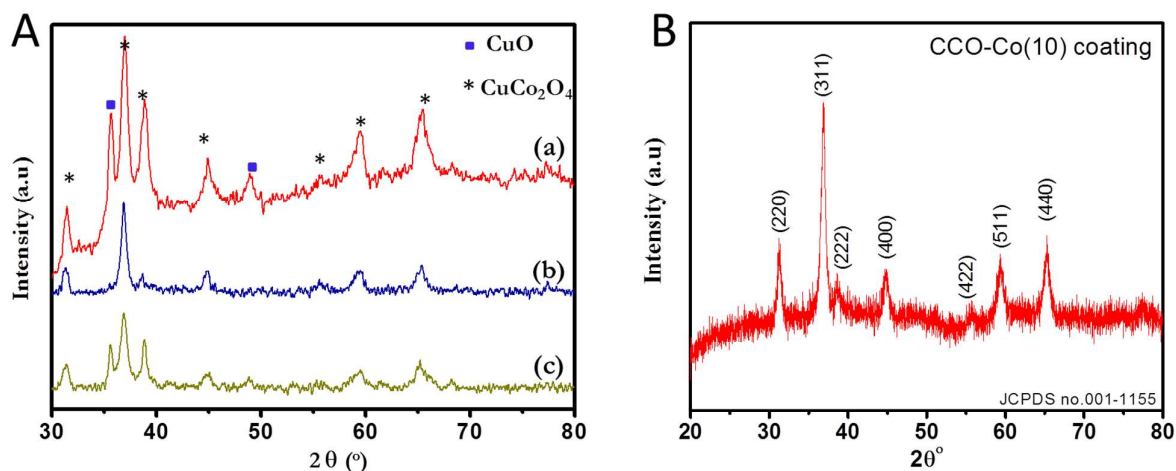
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**Keywords:** Ternary oxide, off-Stoichiometry, nanowalls, room temperature, sensing,  $\text{NH}_3$ .

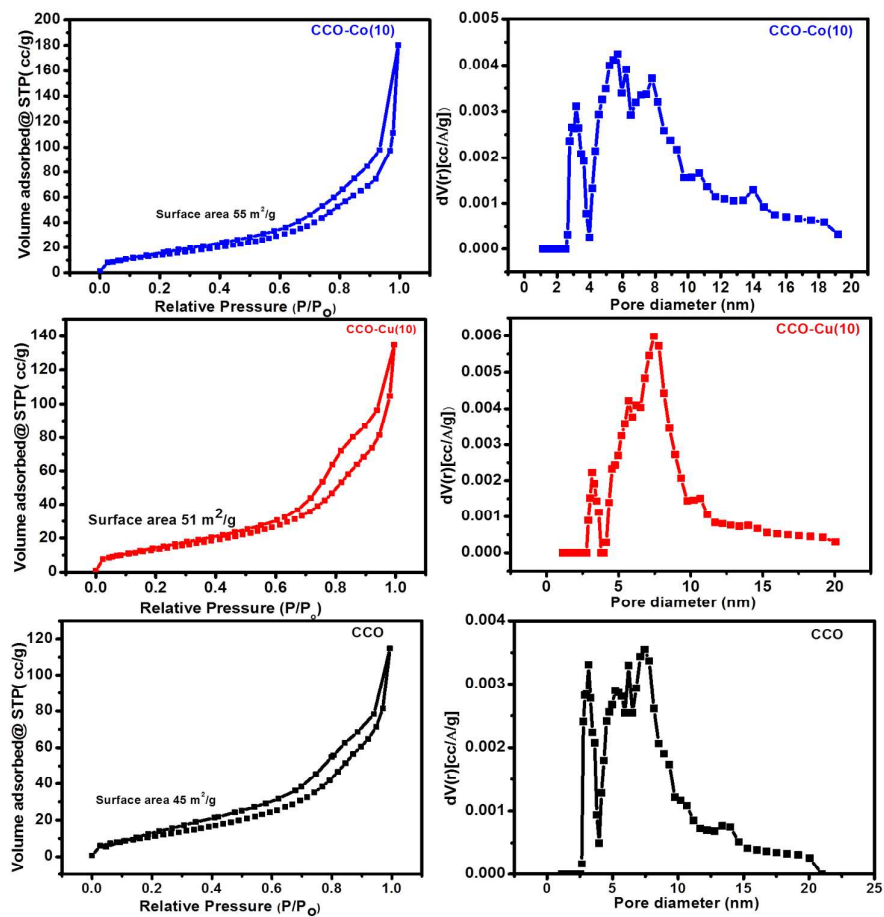


**Figure S1** (a)Schematic diagram (b) Laboratory gas sensing set up



**Figure S2:** (A) X-ray diffraction data for the samples (a) CCO-S (stoichiometric concentration of precursors in reaction vessel), (b) CCO-Co (10 at%. excess cobalt precursor), and (c) CCO-Cu (10 at.% excess copper precursor) (B) X-ray diffraction pattern of CCO-Co(10) coating used for sensing in present work.

[Figure S2(A) is reprinted from Materials Research Bulletin, 90 / n/a, Monika Bhardwaj, Anil Suryawanshi, Rohan Fernandes, Surendar Tonda, Abhik Banerjee, Dushyant Kothari, Satishchandra Ogale,  $\text{CuCo}_2\text{O}_4$  nanowall morphology as Li-ion battery anode: Enhancing electrochemical performance through stoichiometry control, 303-310., Copyright (2017), with permission from Elsevier]



**Figure S3.** BET graphs and pore size distribution of respective sensing materials

**Table S1.** A comparative analysis of gas sensing response of different materials.

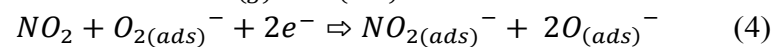
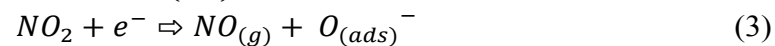
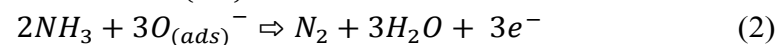
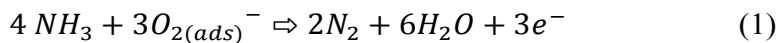
Metal oxides	NH <sub>3</sub> (ppm)	Temp.	Response time	Response/formula used	Ref.
In <sub>2</sub> O <sub>3</sub>	20	RT	<20s	2500/( $\Delta R/R_0$ *100)	(1)
NiO	30	RT	27 s/ (recovery in IR lamp)	0.3/( $\Delta R/R_0$ )	(2)
NiO/ZnO	50	RT	30 s	0.5/( $\Delta R/R_0$ )	(3)
Beta-Ga <sub>2</sub> O <sub>3</sub>	0.5	RT	40 s	19/( $\Delta R/R_0$ *100)	(4)
CNT	100	RT	60 s (not complete recovery)	0.25/( $\Delta R/R_0$ )	(5)
<b>CCO-Co(10)</b>	<b>400</b>	<b>RT</b>	<b>120 s</b>	<b>7.9/(<math>\Delta R/R_0</math>*100)</b>	<b>This work</b>
SnO <sub>2</sub> /MWCNT	1000	RT	<300 s	27.5/( $R_g/R_a$ )	(6)
Au-CNT	500	RT	300 s	4.18( $\Delta R/R_a$ * 100)	(7)
CuO	100	200°C	360 s	3 ( $R_g/R_a$ )	(8)
Fe <sub>2</sub> O <sub>3</sub> -ZnO	0.4	RT	500s/70 s	80/( $I_g/I_a$ )	(9)
SWCNT	40	RT	10 min	5 ( $\Delta R/R_a$ * 100)	(10)
CuO	60	250°C	13 min	19.85 ( $\Delta R/R_a$ * 100)	(11)
PANI	92	RT	13.9 min	7.10( $\Delta R/R_a$ * 100)	(12)
PPy-TiO <sub>2</sub> /ZnO	450	RT	15 min	35( $\Delta R/R_a$ * 100)	(13)
Co <sub>3</sub> O <sub>4</sub>	50	240°C	21 min	31 ( $\Delta R/R_a$ )	(14)

## Gas sensing mechanism

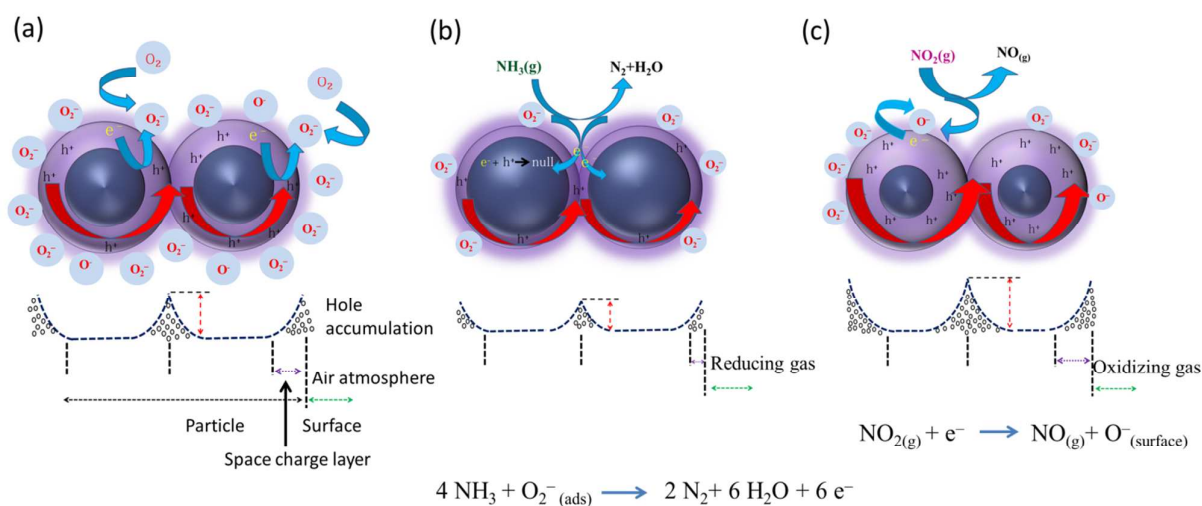
The gas sensing mechanism in the present case can be described by using adsorption of oxygen molecules on the surface of oxides and subsequent reaction of adsorbed oxygen molecules with analyte gas molecules. At low temperature  $<150^{\circ}\text{C}$ , the adsorbed oxygen has  $\text{O}_2^-$  character<sup>15</sup> while it possesses  $\text{O}^-$  character in the temperature range between  $150^{\circ}\text{C}$  and  $400^{\circ}\text{C}$ . Above  $400^{\circ}\text{C}$  oxygen has the  $\text{O}^{2-}$  character. Therefore The gas sensing mechanism at room temperature ( $23^{\circ}\text{C}$  in this case) is predominantly due to the reaction between  $\text{O}_{2(\text{ads})}^-$  and analyte gas molecules.

The gas sensing performance is governed by two processes namely the receptor function and the transducer function which involves interaction of the analyte with a sensor which results in variation in charge carriers and subsequent transport of these charge carries in the sensor.<sup>16</sup> In the present case, nanoporous nanoplatelets are constituted by nanograin particles. The electronic transport between nanograins is governed by grain boundary barrier. Apart from that different factors such as trap states at the grain boundaries and defect states in the semiconductor can also affect the electron transport between the nanograins. The gas sensing mechanism for nanograins based p-type sensor can also be explained using variation in the charge accumulation layer around the nanograins and potential barrier between nanograins (Figure 4) S4 p-type materials, adsorption of oxygen species on the nanograin surface leads to abstraction of electrons from the surface resulting in the formation holes. These holes present beneath the surface of nanograins lead to the formation of a hole-accumulation layer around the nanograins [Figure 4(a)]. Therefore, transport takes place through a hole-accumulated layer around the grains (shown by the red arrow in Figure 4). Thus, increase in the width of a hole-accumulation layer leads to a decrease in the potential barrier for holes, facilitating the charge transport. When reducing gas (here,  $\text{NH}_3$ ) is passed over the sensor, the reducing gas interacts with the adsorbed oxygen anions which lead to the removal of oxygen from the sensor surface, releasing the electrons back into the nanograins. Thus the electrons and holes recombine which leads to a reduction in the width of the hole accumulation layer and increases the potential barrier height between the grains for hole transport due to which the resistance of the sensor increases [Figure 4(b)].

When an oxidizing gas (like  $\text{NO}_2$ ) is passed over the sensor, the width of a hole accumulation layer further increases by the extraction of the electrons from the nanograins; as a result, the sensor resistance decreases due to the increase in the electronic transport channel around the grain. The simplified surface reactions for  $\text{NH}_3$  and  $\text{NO}_2$  are given as follows<sup>2</sup>,



Similar kinds of gas sensing reactions take place in the case of CCO and CCO-Cu(10).



**Figure S 4.** (a, b, c) Schematics illustrating gas sensing mechanism in the presence of reducing and oxidizing gases.

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